FAIRCHILD

SEMICONDUCTOR®

FDD8444L_F085

N-Channel PowerTrench[®] MOSFET

40V, 50A, 6.0m Ω

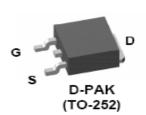
Features

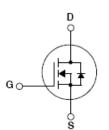
- Typ $r_{DS(on)}$ = 3.8m Ω at V_{GS} = 5V, I_D = 50A
- Typ Q_{g(tot)} = 46nC at V_{GS} = 5V
- Low Miller Charge
- Low Q_{rr} Body Diode
- UIS Capability (Single Pulse/ Repetitive Pulse)
- Qualified to AEC Q101
- RoHS Compliant



Applications

- Automotive Engine Control
- Powertrain Management
- Solenoid and Motor Drivers
- Electronic Transmission
- Distributed Power Architecture and VRMs
- Primary Switch for 12V and 24V systems





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January 2009

MOSF	ET Maximum Ratings $T_{C} = 25^{\circ}C$ unless otherwise	noted		
Symbol	Parameter		Ratings	Units
V _{DSS}	Drain to Source Voltage		40	V
V _{GS}	Gate to Source Voltage		±20	V
	Drain Current Continuous (T _C < 150°C, V _{GS} = 10V)	(Note 1)	50	
I _D	Continuous (T_{amb} = 25°C, V_{GS} = 10V, with $R_{\theta JA}$ = 52°C/W)		16	А
	Pulsed		See Figure 4	
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	295	mJ
	Power Dissipation		153	W
PD	Derate above 25°C		1.02	W/ºC
T _J , T _{STG}	Operating and Storage Temperature		-55 to +175	°C

Thermal Characteristics

R_{\thetaJC}	Thermal Resistance, Junction to Case	0.98	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient TO-252, 1in ² copper pad area	52	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD8444L	FDD8444L_F085	TO-252AA	13"	12mm	2500 units

Electrical Characteristics T_J = 25°C unless otherwise noted

Symbol Parameter lest Conditions Min Typ Max Units	O	Demonster	To all Q and shift and a		T		11
	Symbol		Test Conditions	Min	Тур	Max	Units

Off Characteristics

B _{VDSS}	Drain to Source Breakdown Voltage	I _D = 250μA, V _{GS}	$I_{D} = 250 \mu A, V_{GS} = 0V$		-	-	V
	Zara Cata Valtaga Drain Current	V _{DS} = 32V,		-	-	1	A
DSS	I _{DSS} Zero Gate Voltage Drain Current	$V_{GS} = 0V$	T _J = 150 ^o C	-	-	250	μA
I _{GSS}	Gate to Source Leakage Current	V _{GS} = ±20V		-	-	±100	nA

On Characteristics

V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$	1	1.8	3	V
		I _D = 50A, V _{GS} = 10V	-	3.5	5.2	
		I _D = 50A, V _{GS} = 5V	-	3.8	6.0	
r _{DS(on)}	Drain to Source On Resistance	I _D = 50A, V _{GS} = 4.5V	-	4.0	6.5	mΩ
		I _D = 50A, V _{GS} = 5V, T _J = 175 ^o C	-	6.8	10.7	

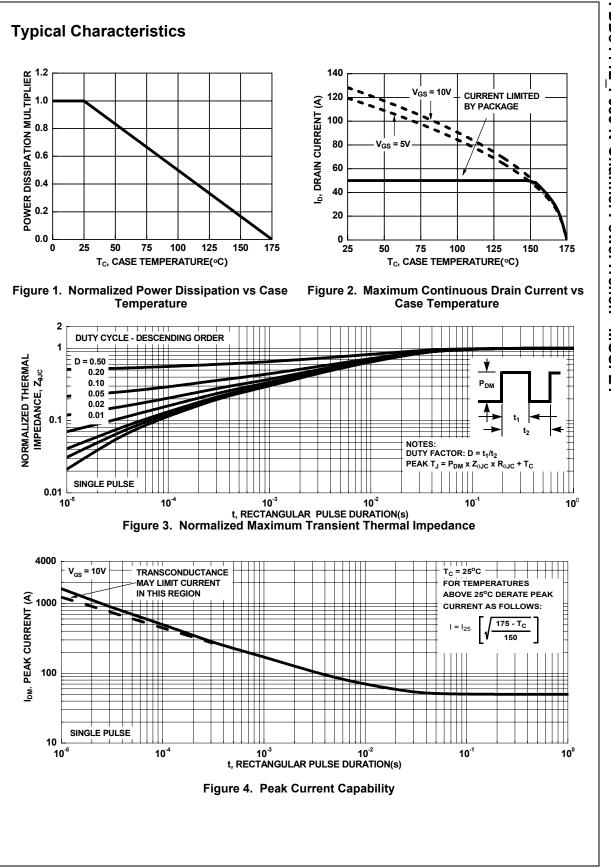
Dynamic Characteristics

C _{iss}	Input Capacitance		$V_{DS} = 25V, V_{GS} = 0V,$		5530	-	pF
C _{oss}	Output Capacitance	V _{DS} = 25V, V _{GS} = f = 1MHz			605	-	pF
C _{rss}	Reverse Transfer Capacitance			-	400	-	pF
R _G	Gate Resistance	f = 1MHz		-	1.7	-	Ω
Q _{g(TOT)}	Total Gate Charge at 5V	V_{GS} = 0 to 5V		-	46	60	nC
Q _{g(TH)}	Threshold Gate Charge	V_{GS} = 0 to 2V	V _{DD} = 20V	-	5.4	7	nC
Q _{gs}	Gate to Source Gate Charge		I _D = 50A	-	16.3	-	nC
Q _{gs2}	Gate Charge Threshold to Plateau		I _g = 1.0mA	-	10.9	-	nC
Q _{gd}	Gate to Drain "Miller" Charge			-	21	-	nC

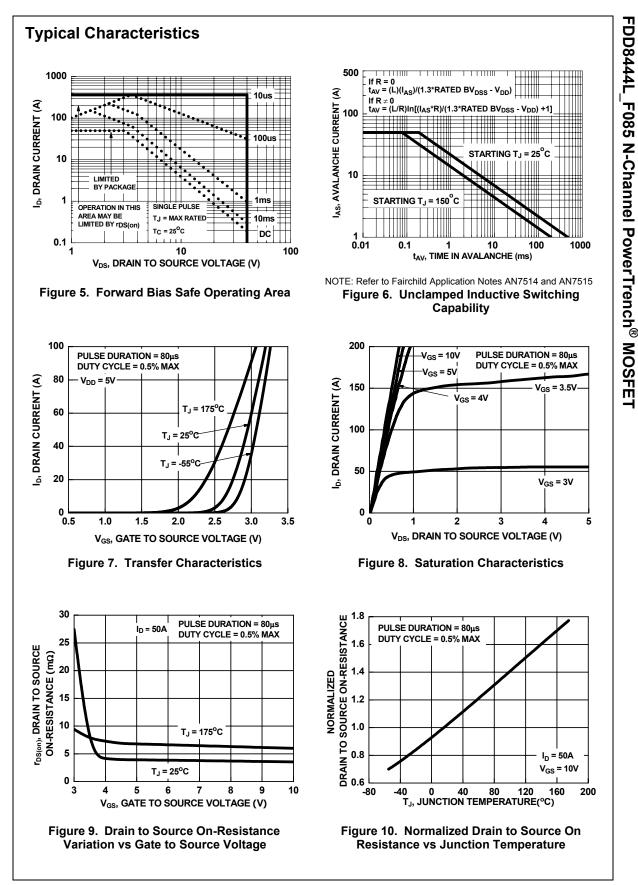
	Parameter	Test Conditions	Min	Тур	Max	Units
Switch	ing Characteristics					
on	Turn-On Time		-	-	104	ns
d(on)	Turn-On Delay Time		-	18.7	-	ns
t _r	Turn-On Rise Time	$V_{DD} = 20V, I_D = 50A$	-	46	-	ns
d(off)	Turn-Off Delay Time	—V _{GS} = 5V, R _{GS} = 2Ω	-	42	-	ns
lf	Turn-Off Fall Time		-	19.2	-	ns
off	Turn-Off Time		-	-	96	ns
	ource Diode Characteristics	I _{SD} = 50A	-	0.9	1.25	
V _{SD}	Source to Drain Diode Voltage	I _{SD} = 25A	-	0.8	1.0	V
rr	Reverse Recovery Time	I _F = 50A, dI _F /dt = 100A/μs	-	34	44	ns
Q _{rr}	Reverse Recovery Charge	—— I _F = 50A, dI _F /dt = 100A/μs	-	29	38	nC

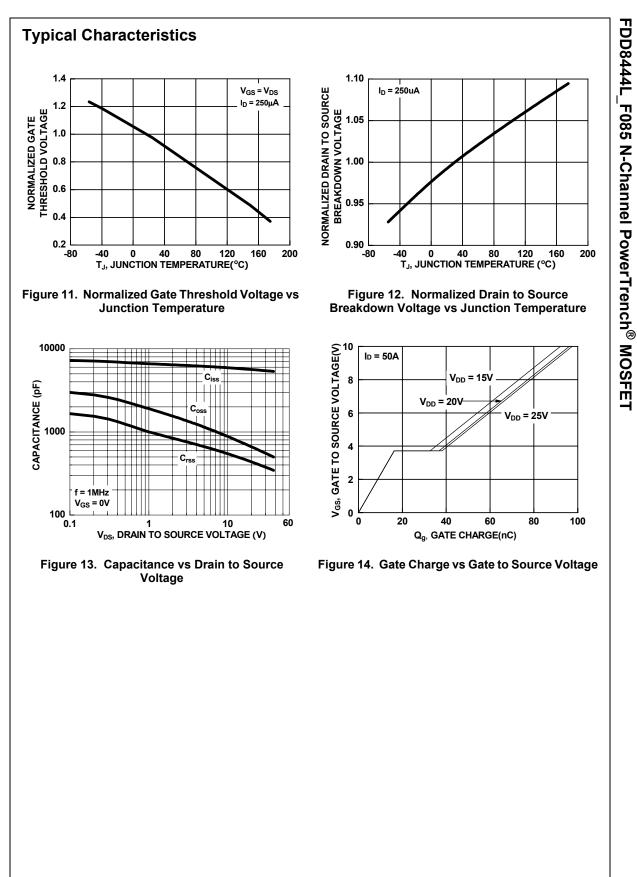
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This product has been designed to meet the extreme test conditions and environment demanded by the automotive industry. For a copy of the requirements, see AEC Q101 at: http://www.aecouncil.com/ All Fairchild Semiconductor products are manufactured, assembled and tested under ISO9000 and QS9000 quality systems certification.



FDD8444L_F085 N-Channel PowerTrench[®] MOSFET





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